

HGU2

2kV, 10A, 50nS Modular "Hi-Bel" Rectifier Assemblies

Features

- High Voltage, High Current Capability
- Large Plated Brass Base-Plate Heat Sink on Cathode Side
- Can Be Easily Cascaded for Higher Voltage System Applications
- Molded Encapsulation, ANSI/UL94 V-0 Rated Material



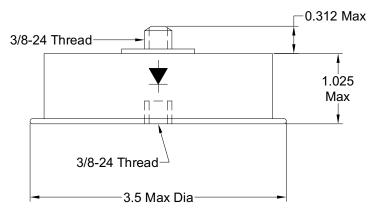
Specifications¹

Part	V _{RRM}	I _{FAVM}	V _F	Ι _R	I _{FSM}	T _{RR}
Number	V	A	V	μΑ		nS
HGU2	2000	10	6	10	250	50

Temperature °C				
Operating Temperature	-55 to 150			
Storage Temperature	-55 to 150			
Maximum Junction Temperature	150			

¹25°C ambient temperature unless stated otherwise.

Drawings



Dimensions in inches, tolerances ± 0.020 except as noted

Specification Definitions

	Specifications	Conditions
V_{RRM}	Maximum Repetitive Reverse Voltage	-
IFAVM	Maximum Average Forward Current	At T _C = 75°C
V _F	Maximum Forward Voltage Drop	At I _{FAVM}
I _R	Maximum Leakage Current	At V _{RRM}
I _{FSM}	Maximum Surge Current	At 8.3 mS, Single Half Sine
TRR	Maximum Reverse Recovery Time	$I_F = 0.5A$; $I_R = -1.0A$; $I_{RR} = -0.25A$

Note: Specifications subject to change without notice. Photo is representation only.





VERSION: 2.0

Effective: 22 December 2021

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